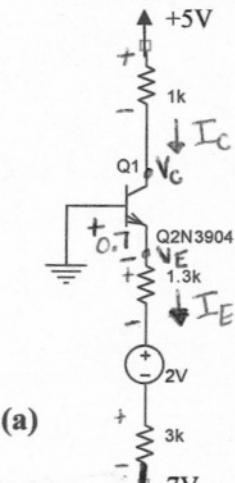
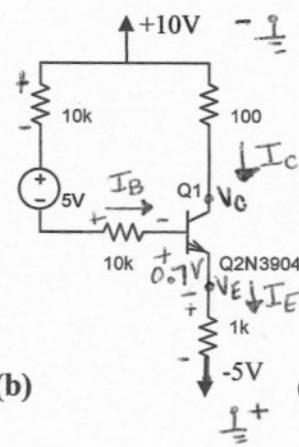


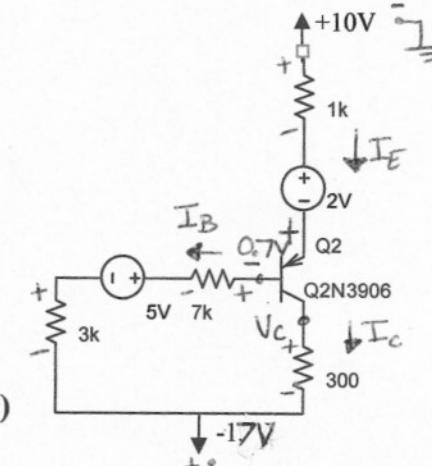
1. Use $|V_{BE}|=0.7$, $\beta=100$. Find voltages at all nodes and currents through all branches. (worth 4 problems)



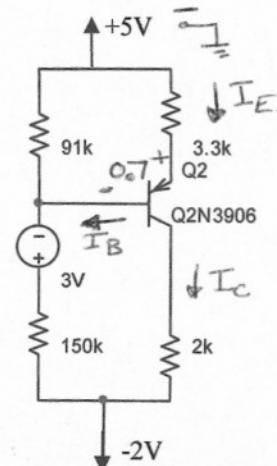
(a)



(b)



(c)



Assume Active: $+1$

$$Q. +0.7 + 1.3k(I_E) + 2 + 3k(I_E) - 7 = 0$$

$$I_E = \frac{(5 - 0.7)}{4.3k} = 1 \text{ mA}$$

$$-7 + I_E(3k) + 2 + I_E(1.3k) - V_E = 0$$

$$V_E = -5 + I_E(4.3k) = -0.7 \text{ V}$$

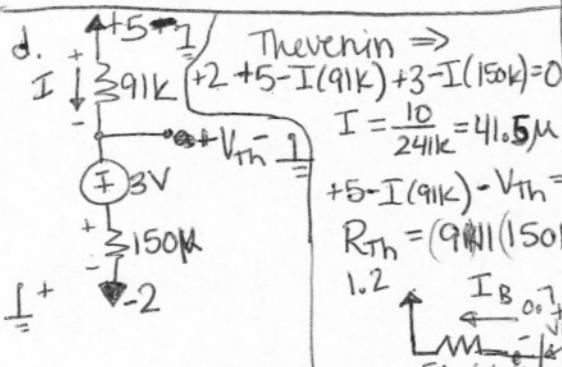
$$I_C = \alpha I_E = \frac{100}{101}(1 \text{ mA}) = 0.99 \text{ mA}$$

$$V_B = 0$$

$$5 - I_C(1k) - V_C = 0$$

$$V_C = 5 - I_C(1k) \approx +4 \text{ V}$$

$V_C > V_B > V_E \rightarrow$ Active mode ✓



$$V_E = 5 - I_E(3.3k) = 2.36 \text{ V}$$

$$V_B = V_E - V_{EB} = 1.66 \text{ V}$$

$$V_C = -2 + I_C(2k) = -0.4 \text{ V}$$

$$b. +10 - I_B(10k) - 5 - I_B(10k) - 0.7 - I_E(1k) + 5 = 0 \quad +1$$

$$I_B = \frac{I_E}{(\beta+1)} \Rightarrow I_E = \frac{9.3}{\left[\frac{20k}{(\beta+1)}\right] + 1k} = 7.76 \text{ mA}$$

$$I_C = \beta \cdot I_B \Rightarrow I_C = \alpha I_E = 7.69 \text{ mA}$$

$$I_B = 76.9 \mu \text{A}$$

$$V_B \approx 5 - I_B(20k) = 3.5 \text{ V}$$

$$V_E \approx -5 + I_E(1k) \approx 2.8 \text{ V}$$

$$V_C = 10 - 100(I_C) = 9.2 \text{ V}$$

$V_C > V_B > V_E$ Active ✓

$$c. +10 - I_E(1k) - 2 - 0.7 - I_B(7k) - 5 - 3k(I_B) + 17 = 0$$

$$I_B = I_E / \beta + 1 \Rightarrow I_E = \frac{19.3}{\left(\frac{10k}{\beta+1}\right) + 1k} = 17.6 \text{ mA}$$

$$I_C = \alpha I_E = 17.4 \text{ mA}$$

$$I_B = I_C / \beta \approx 174 \mu \text{A}$$

$$17 + 3k(I_B) + 5 + 7k(I_B) = V_B \Rightarrow V_B = -12 + 10k(I_B)$$

$$V_B = -10.26 \text{ V}$$

$$V_E \Rightarrow +10 - I_E(1k) - 2 - V_E = 0 \Rightarrow V_E = -9.6 \text{ V}$$

$$-17V + I_C(300) - V_C = 0 \Rightarrow V_C = -11.78 \text{ V}$$

$$V_C < V_B < V_E \checkmark$$

$$R_{Th} = (91k)(150k) = 56.6k$$

$$+5 - I(91k) - V_{Th} = 0 \Rightarrow V_{Th} \approx 1.2 \text{ V}$$

$$I_B = \frac{I_E}{(\beta+1)} \Rightarrow I_E = \frac{3.1}{3.3k + \frac{56.6k}{\beta+1}} = \frac{3.1}{3.3k + 560} = 8 \mu \text{A}$$

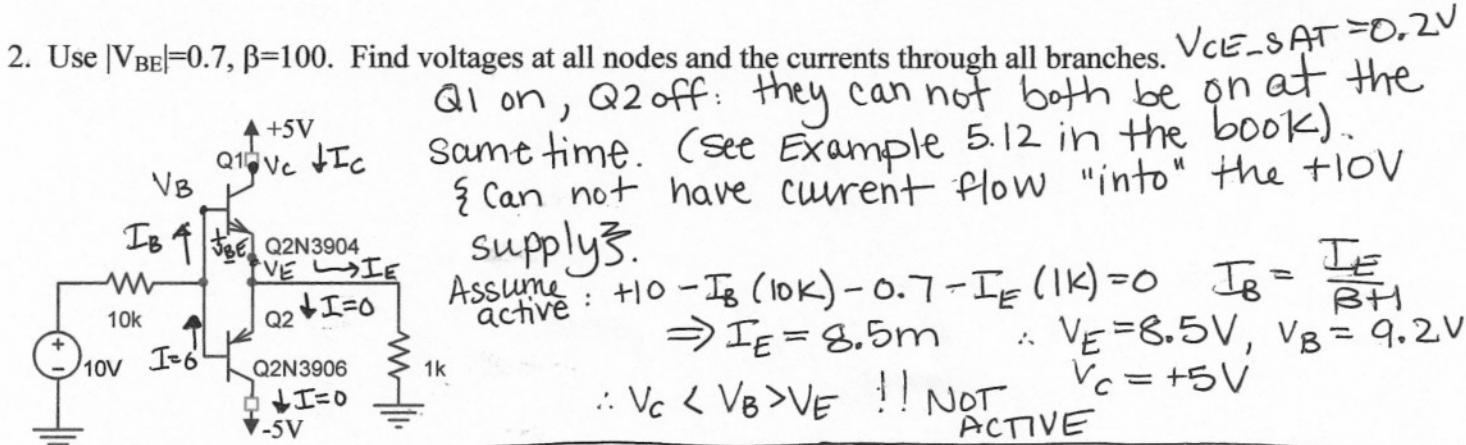
$$+5 - I_E(3.3k) - 0.7 - I_B(56.6k) - 1.2 = 0$$

$$I_E = \frac{3.1}{3.3k + 560} = 8 \mu \text{A}$$

$$I_C = \alpha I_E = \frac{100}{101}(8 \mu \text{A}) \approx 8 \mu \text{A}$$

$$I_B = \frac{I_E}{101} = 8 \mu \text{A}$$

$V_C < V_B < V_E \checkmark$ Active



Assume SAT: $V_{CE} = 0.2 \text{ V}$
 $+5 - V_{CESAT} - I_E (1k) = 0$
 $\therefore V_E = 4.8 \text{ V}$

$$V_B = 4.8 + 0.7 = 5.5 \text{ V}$$

$$I_E = \frac{V_E}{1k} = 4.8 \text{ mA}$$

$$I_B = \frac{(10 - 5.5)}{10k} = 0.45 \text{ mA}$$

$$I_C = I_E - I_B = 4.35 \text{ mA}$$

3. Assume active operation for all transistors. (V_{sig} is an ac source)

Assume that the capacitors act as an open for DC operation.

(a) Find the symbolic equations for the

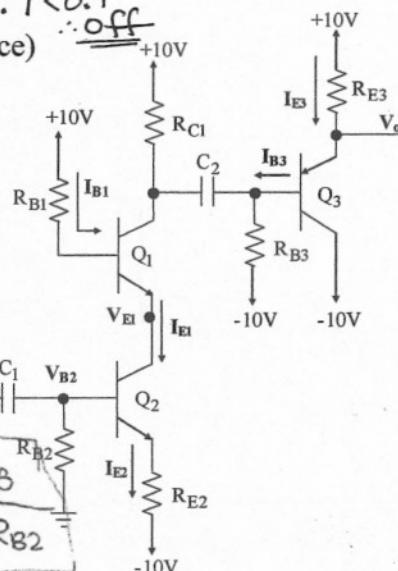
DC values for $I_{E1}, I_{E2}, I_{B1}, I_{E3}, I_{B3}, V_o, V_{E1}$

(b) Draw the hybrid- π or model-T AC circuit

$$-I_{B2}(R_{B2}) - V_{BE} - R_{E2}(I_{E2}) + 10 = 0$$

$$I_{B2} = \frac{I_{E2}}{\beta+1} \Rightarrow I_{E2} = \frac{10 - V_{BE}}{R_{E2} + R_{B2}/\beta+1}$$

$$I_{E1} = I_{C2} = \alpha I_{E2} = \frac{\alpha(10 - V_{BE})}{R_{E2} + R_{B2}/\beta+1} \quad \text{or} \quad \frac{(10 - V_{BE})\beta}{R_{E2}(\beta+1) + R_{B2}}$$



$$I_{B1} = \frac{I_{E1}}{\beta+1} = \frac{(10 - V_{BE})\beta}{R_{E2}(\beta+1)^2 + R_{B2}(\beta+1)}$$

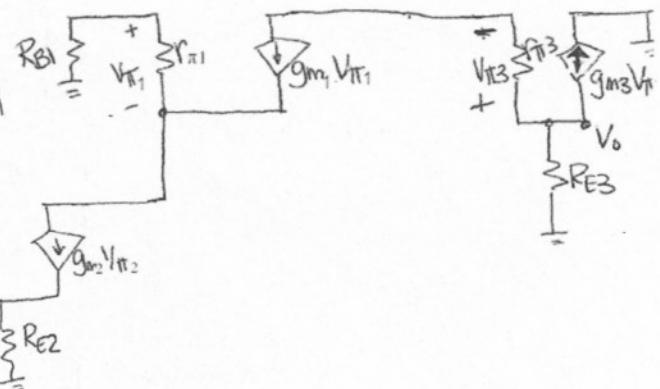
$$-10 + I_{B3}(R_{B3}) + V_{BE} + I_{E3}(R_{E3}) - 10 = 0$$

$$I_{E3} = \frac{20 - V_{BE}}{R_{E3} + R_{B3}/\beta+1}$$

$$I_{B3} = \frac{(20 - V_{BE})}{R_3(\beta+1) + R_{B3}}$$

$$V_o = 10 - I_{E3} \cdot R_{E3}$$

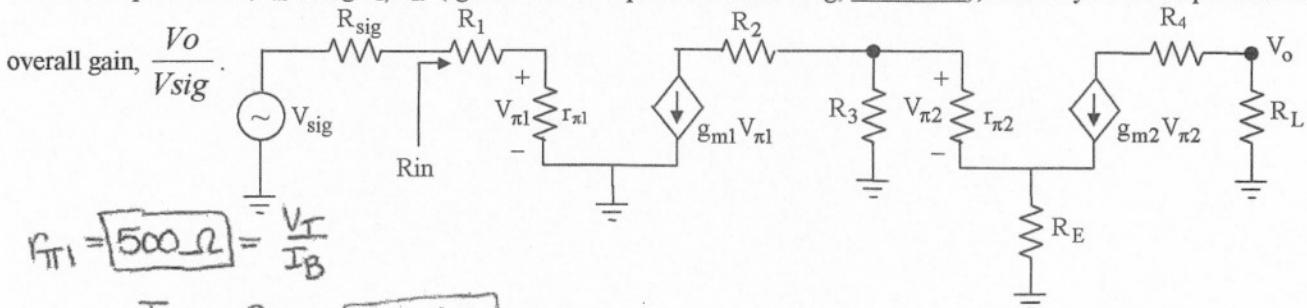
$$(b) V_{E1} = 10 - I_{B1}(R_{B1}) - V_{BE}$$



4. Use $|V_{BE}|=0.7$, $\beta=20$, $V_T=25mV$ (V_{sig} is an ac source), ignore r_o .

This small-signal model circuit is shown below. It was found through a DC analysis that $I_{C1}=1mA$ and $I_{C2}=2mA$.

Find the ac parameters, $r_{\pi 1}$ and g_{m2} , R_{in} . (Ignore the AC input source and R_{sig} , include R_1). Find a symbolic expression for the overall gain, $\frac{V_o}{V_{sig}}$.



$$r_{\pi 1} = \boxed{500\Omega} = \frac{V_T}{I_B}$$

$$g_{m2} = \frac{I_{C2}}{V_T} = \frac{2m}{25m} = \boxed{80mA/V}$$

$$R_{in} = R_1 + r_{\pi 1}$$

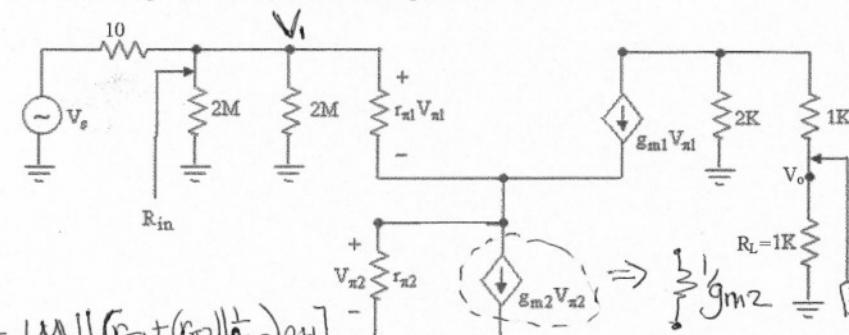
$$V_o = -g_{m2} V_{\pi 2} \cdot R_L$$

$$V_{\pi 2} = -g_{m1} V_{\pi 1} (R_3) \\ [R_3 + r_{\pi 2} + R_E(\beta+1)] \cdot r_{\pi 2}$$

$$V_{\pi 1} = \frac{V_{sig} (r_{\pi 1})}{(r_{\pi 1} + R_1 + R_{sig})}$$

$$\frac{V_o}{V_{sig}} = \frac{-g_{m2} R_L (r_{\pi 1}) (-g_{m1}) (R_3) (\beta+1)}{(r_{\pi 1} + R_1 + R_{sig})(R_3 + r_{\pi 2} + R_E(\beta+1))}$$

5. Use $|V_{BE}|=0.7$, $\beta=100$, $V_T=25mV$ (V_s is an ac source), ignore r_o . This small-signal model comes from a circuit that has 2 transistors Q1 and Q2 denoted below as subscripts 1 and 2. It was found that $I_{E1}=2.525m$ and $I_{E2}=1.2625m$. Find R_{in} (ignore V_s and 10Ω), R_{out} (ignore R_L), and midband gain, V_o/V_s .



$$R_{in} = 1M \parallel (r_{\pi 1} + (r_{\pi 2} \parallel g_{m2}) \beta + 1)$$

$$R_{in} \approx \boxed{2,991\Omega}$$

$$V_o = \left[-g_{m1} V_{\pi 1} (2K) \right] \parallel K$$

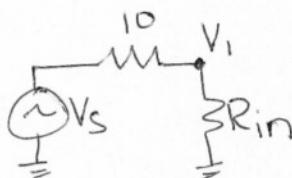
AC parameters \Rightarrow

$$r_{\pi 1} = \frac{V_T}{I_B} = \frac{25m}{(2.525m)} = 1,000\Omega$$

$$g_{m1} = \frac{I_{C1}}{V_T} \approx 100mA/V$$

$$r_{\pi 2} = \frac{25m}{(1.2625m)} \approx 2K\Omega$$

$$g_{m2} = \frac{I_{C2}}{V_T} \approx 50mA/V$$



$$V_i = \frac{V_s (R_{in})}{R_{in} + 10} \approx V_s$$

$$V_{\pi 1} \parallel r_{\pi 1}$$

$$V_{\pi 1} = \frac{V_i (r_{\pi 1})}{r_{\pi 1} + 2K} = 0.33V_i$$

$$3[r_{\pi 2} \parallel g_{m2}] (\beta + 1) = 2K \quad \therefore V_o = -g_{m1} (50)(0.33V_i)$$

$$\frac{V_o}{V_s} \approx \boxed{-16.7V/V}$$